## N-Channel 30-V (D-S) MOSFET

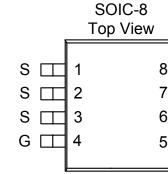
These miniature surface mount MOSFETs utilize a high cell density trench process to provide low  $r_{DS(on)}$  and to ensure minimal power loss and heat dissipation. Typical applications are DC-DC converters and power management in portable and battery-powered products such as computers, printers, PCMCIA cards, cellular and cordless telephones.

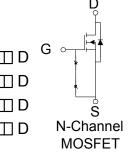
- Low r<sub>DS(on)</sub> provides higher efficiency and extends battery life
- Low thermal impedance copper leadframe SOIC-8 saves board space
- Fast switching speed
- High performance trench technology



## PRODUCT SUMMARY

V <sub>DS</sub> (V)	$r_{\mathrm{DS(on)}} m(\Omega)$	I <sub>D</sub> (A)
30	$22 @ V_{GS} = 10V$	9.4
	$30 @ V_{GS} = 4.5V$	7.0





ABSOLUTE MAXIMUM RATINGS ( $T_A = 25$ °C UNLESS OTHERWISE NOTED)					
Parameter			Maximum	Units	
Drain-Source Voltage		$V_{DS}$	30	V	
Gate-Source Voltage		V <sub>GS</sub>	±20	v	
Continuous Drain Current <sup>a</sup>	$T_{A}=25^{\circ}C$ $T_{A}=70^{\circ}C$	J.	9.4		
Continuous Drain Current	$T_A=70^{\circ}C$	ID	7.4	А	
Pulsed Drain Current <sup>b</sup>		I <sub>DM</sub>	±30		
Continuous Source Current (Diode Conduction) <sup>a</sup>		Is	1.6	А	
Power Dissipation <sup>a</sup>	$T_{A}=25^{\circ}C$ $T_{A}=70^{\circ}C$	Pp	3.1	W	
	$T_A=70^{\circ}C$	I D	2	vv	
Operating Junction and Storage Temperature Range			-55 to 150	°C	

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Maximum Uni		
	t <= 10 sec	D	50	°C/W	
Maximum Junction-to-Ambient <sup>a</sup>	Steady State	$R_{\theta JA}$	92	°C/W	

Notes

a. Surface Mounted on 1" x 1" FR4 Board.

b. Pulse width limited by maximum junction temperature

SPECIFICATIONS ( $T_A = 25^{\circ}$ C UNLESS OTHERWISE NOTED)						
Denemator	6 h l		Limits			TI *4
Parameter	Symbol	<b>Test Conditions</b>		Тур	Max	Unit
Static						
Gate-Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_D = 250 \text{ uA}$	1			V
Gate-Body Leakage	I <sub>GSS</sub>	$V_{DS} = 0 V, V_{GS} = \pm 20 V$			±100	nA
Zero Gate Voltage Drain Current	I <sub>DSS</sub> -	$V_{DS} = 24 V, V_{GS} = 0 V$			1	uA
Zero Gate Voltage Drain Current		$V_{DS} = 24 V, V_{GS} = 0 V, T_J = 55^{\circ}C$			25	
On-State Drain Current <sup>A</sup>	I <sub>D(on)</sub>	$V_{DS} = 5 V, V_{GS} = 10 V$	20			Α
Drain-Source On-Resistance <sup>A</sup>	r <sub>DS(on)</sub>	$V_{GS} = 10 \text{ V}, I_D = 9.2 \text{ A}$			22	mΩ
Drain-Source On-Resistance		$V_{GS} = 4.5 \text{ V}, I_D = 7 \text{ A}$			30	
Forward Tranconductance <sup>A</sup>	$g_{fs}$	$V_{DS} = 15 \text{ V}, I_D = 9.2 \text{ A}$		40		S
Diode Forward Voltage	V <sub>SD</sub>	$I_{\rm S} = 2.3$ A, $V_{\rm GS} = 0$ V		0.7		V
Dynamic <sup>b</sup>						
Total Gate Charge	Qg	$V_{DS} = 10 \text{ V}, V_{GS} = 4.5 \text{ V},$ $I_D = 7 \text{ A}$		4.0		nC
Gate-Source Charge	Q <sub>gs</sub>			1.1		
Gate-Drain Charge	Q <sub>gd</sub>			1.4		
Turn-On Delay Time	t <sub>d(on)</sub>			16		
Rise Time	t <sub>r</sub>	$V_{DD}$ = 10 V, $R_L$ = 6 $\Omega$ , ID = 1 A,		5		nS
Turn-Off Delay Time	t <sub>d(off)</sub>	$V_{GEN} = 10 V$		23		115
Fall-Time	t <sub>f</sub>			3		

Notes

a. Pulse test:  $PW \le 300$ us duty cycle  $\le 2\%$ .

b. Guaranteed by design, not subject to production testing.

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